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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/071,908	02/08/2002	David William Kinnard	00-SM5-0142 (ATI-0009)	2272
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CANTOR COLBURN, LLP 55 GRIFFIN ROAD SOUTH BLOOMFIELD, CT 06002			ZERVIGON, RUDY	
			ART UNIT	PAPER NUMBER
			1763	
DATE MAILED: 03/21/2006				

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

10/071,908

Applicant(s)

KINNARD ET AL.

Examiner

Rudy Zervigon

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 09 January 2006.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-21 and 32-36 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-21 and 32-36 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
- ☐ Certified copies of the priority documents have been received.
 - ☐ Certified copies of the priority documents have been received in Application No. _____.
 - ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

1. In view of the appeal brief filed on January 9, 2006, PROSECUTION IS HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

(1) file a reply under 37 CFR 1.111 (if this Office action is non-final) or a reply under 37 CFR 1.113 (if this Office action is final); or,

(2) initiate a new appeal by filing a notice of appeal under 37 CFR 41.31 followed by an appeal brief under 37 CFR 41.37. The previously paid notice of appeal fee and appeal brief fee can be applied to the new appeal. If, however, the appeal fees set forth in 37 CFR 41.20 have been increased since they were previously paid, then appellant must pay the difference between the increased fees and the amount previously paid.

A Supervisory Patent Examiner (SPE) has approved of reopening prosecution by signing below:

Claim Rejections - 35 USC § 103

2. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

3. Claims 1-4, 6, 10-16, 21, and 32-36 rejected under 35 U.S.C. 103(a) as being unpatentable over Halpin; Michael W. (US 6143079 A) and Tanaka; Hitoshi (US 5091207 A) in view of Hoke; William E. et al (US 5077875 A). Halpin; Michael W. (US 6143079 A) teaches a reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9)

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comprising: a base unit (18; Figure 2, 4); a chuck assembly (36; Figure 2) disposed in a cavity (32; Figure 2) of the base unit (18; Figure 2, 4), wherein the chuck assembly (36; Figure 2) comprises a support (36/56 interface; Figure 2) having a surface capable of receiving a substrate (56; Figure 3,4); a process chamber (portion 108 of 10; Figure 4) comprising a top wall (12 - quartz; Figure 2,4; column 5; lines 49-59), a bottom wall (14; Figure 4), and sidewalls (inner surface of 108; Figure 4) extending therefrom substantially perpendicular to the support surface (36/56 interface; Figure 2) of said chuck assembly (36; Figure 2), and a cylindrical opening (along length between 12 and 14; Figure 4) extending through the bottom wall (14; Figure 4) to the top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) defining a substantially cylindrically shaped interior region having a central axis extending substantially perpendicular to the support surface (36/56 interface; Figure 2) of said chuck assembly (36; Figure 2), wherein the process chamber (portion 108 of 10; Figure 4) is coupled to the base unit (18; Figure 2, 4) – claim 1

Halpin further teaches:

- i. an inlet manifold assembly (112, 114, 116; Figure 2) in fluid communication with a first sidewall opening (94; Figure 2) of the process chamber (portion 108 of 10; Figure 4) in a selected one of the sidewalls (inner surface of 108; Figure 4), and an exhaust manifold assembly (120; Figure 2) in fluid communication with a second sidewall opening (74; Figure 3,4) of the process chamber (portion 108 of 10; Figure 4) in the sidewall diametrically opposed from the selected one of the sidewalls (inner surface of 108; Figure 4) – claim 1
- ii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the top wall (12 - quartz; Figure 2,4; column 5;

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- lines 49-59) of the process chamber (portion 108 of 10; Figure 4) is removable, as claimed by claim 4
- iii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the exhaust manifold (124; Figure 2) assembly is adapted to receive the gas and/or reactant flow from the process chamber (portion 108 of 10; Figure 4) at about a plane parallel to the surface of the substrate (56; Figure 3,4), as claimed by claim 6
- iv. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the support (36/56 interface; Figure 2) of the chuck assembly (36; Figure 2) is stationary and non-rotating, as claimed by claim 10. Further, it has been held that claim language that simply specifies an intended use or field of use for the invention generally will not limit the scope of a claim (Walter , 618 F.2d at 769, 205 USPQ at 409; MPEP 2106). Additionally, in apparatus claims, intended use must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim (In re Casey, 152 USPQ 235 (CCPA 1967); In re Otto , 136 USPQ 458, 459 (CCPA 1963); MPEP 2111.02).
- v. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) is substantially transparent to a light source (89; Figure 2), as claimed by claim 12

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- vi. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) is substantially transparent to a UV light source (89; Figure 2), as claimed by claim 13
- vii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) is substantially transparent to an infrared light source (89; Figure 2), as claimed by claim 14
- viii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the process chamber (portion 108 of 10; Figure 4) includes a third sidewall opening (26; Figure 3) in the sidewall adjacent to the first (22; Figure 3) and second (24; Figure 3) sidewall openings, wherein the third opening (26; Figure 3) is sized for transporting the substrate (56; Figure 3,4) into an interior region of the process chamber (portion 108 of 10; Figure 4), as claimed by claim 15
- ix. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the inlet manifold assembly (112, 114, 116; Figure 2) is adapted to introduce the gas and/or reactants at about a plane parallel to a surface of the substrate (56; Figure 3,4) and the exhaust manifold assembly (120; Figure 2) is adapted to exhaust the gas and/or reactants at about a plane parallel to a surface of the substrate (56; Figure 3,4), as claimed by claim 21
- x. A reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) comprising: a base unit (18; Figure 2, 4); a chuck assembly (36; Figure 2)

disposed in a cavity (32; Figure 2) of the base unit (18; Figure 2, 4), wherein the chuck assembly (36; Figure 2) comprises a support (36/56 interface; Figure 2) having a surface capable of receiving a substrate (56; Figure 3,4); a process chamber (portion 108 of 10; Figure 4) comprising a transparent top wall (12 - quartz; Figure 2,4; column 5; lines 49-59), a bottom wall (14; Figure 4), and sidewalls (inner surface of 108; Figure 4) extending therefrom, and a cylindrical opening (along length between 12 and 14; Figure 4) extending through the bottom wall (14; Figure 4) to top the wall to define a substantially cylindrically shaped interior region, wherein the process chamber (portion 108 of 10; Figure 4) is coupled to the base unit (18; Figure 2, 4); a light source (89; Figure 2) assembly in operable communication with the transparent top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) for projecting radiation into the process chamber (portion 108 of 10; Figure 4) – claim 32

- xi. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) of Claim 32, wherein the light source (89; Figure 2) assembly comprises a housing (8; Figure 2) and a light source (89; Figure 2), as claimed by claim 33
- xii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) of Claim 32, wherein the top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) comprises a quartz material, as claimed by claim 34
- xiii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) of Claim 32, wherein the exhaust manifold assembly (120; Figure 2) is adapted to receive the gas and/or reactant flow from the process chamber (portion 108 of 10; Figure

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4) at about a plane parallel to a surface of the substrate (56; Figure 3,4), as claimed by claim 35

- xiv. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) of Claim 32, wherein the transparent top wall (12 - quartz; Figure 2,4; column 5; lines 49-59) is removable (Figure 4), as claimed by claim 36

Halpin does not teach:

- i. wherein the first (22; Figure 3) and second (24; Figure 3) sidewall openings define an entire flow path of the gas and/or the reactant flow into and out of the process chamber – claim 1
- ii. wherein the inlet manifold assembly (112, 114, 116; Figure 2) comprises a flow-shaping portion adapted to laterally elongate a gas and/or a reactant flow into the process chamber (portion 108 of 10; Figure 4), wherein the fluid communication between the inlet manifold assembly (112, 114, 116; Figure 2) and the first sidewall opening (94; Figure 2) of the process chamber (portion 108 of 10; Figure 4) is free from a baffle plate – claim 1
- iii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the flow-shaping portion of the inlet manifold assembly (112, 114, 116; Figure 2) is adapted to introduce the gas and/or reactant flow into the process chamber (portion 108 of 10; Figure 4) at about a plane parallel to a surface of the substrate (56; Figure 3,4), as claimed by claim 2
- iv. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the flow-shaping portion is triangularly shaped, as claimed by claim 3

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- v. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the inlet manifold assembly (112, 114, 116; Figure 2) further comprises a flow restrictor attached to an opening of the flow-shaping portion, as claimed by claim 11
- vi. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, further comprising a baffle plate disposed about an opening of the flow-shaping portion (15a; Figure 3), as claimed by claim 16
- vii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the inlet manifold assembly (112, 114, 116; Figure 2) is adapted to introduce the gas and/or reactants at about a plane parallel to a surface of the substrate (56; Figure 3,4) and the exhaust manifold assembly (120; Figure 2) is adapted to exhaust the gas and/or reactants at about a plane parallel to a surface of the substrate (56; Figure 3,4), as claimed by claim 21
- viii. an inlet manifold assembly (112, 114, 116; Figure 2) in fluid communication with a first sidewall opening (94; Figure 2) of the process chamber (portion 108 of 10; Figure 4) in a selected one of the sidewalls (inner surface of 108; Figure 4), wherein the inlet manifold assembly (112, 114, 116; Figure 2) comprises a flow-shaping portion adapted to laterally elongate a gas and/or a reactant flow into the process chamber (portion 108 of 10; Figure 4), wherein the fluid communication between the inlet manifold assembly (112, 114, 116; Figure 2) and the first sidewall opening (94; Figure 2) of the process chamber (portion 108 of 10; Figure 4) is free from a baffle plate; and an exhaust manifold assembly (120; Figure 2) in fluid communication with a second sidewall opening (74; Figure 3,4) of the

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process chamber (portion 108 of 10; Figure 4) in the sidewall diametrically opposed from the selected one of the sidewalls (inner surface of 108; Figure 4) – claim 32

Tanaka teaches a similar CVD apparatus (Figure 8) including a dynamic exhaust control system (V1-V4, “MC”; Figure 4; column 4, lines 31-58).

Hoke; William E. et al (US 5077875 A) teaches a similar CVD apparatus (Figure 3) including:

- ix. an inlet manifold assembly (14, 15a, not including 12; Figure 3) in fluid communication with a first sidewall opening (12; Figure 3) of the process chamber (11; Figure 3) in a selected one of the sidewalls (12; Figure 3), and an exhaust manifold assembly (13, 16, 17; Figure 3) in fluid communication with a second sidewall opening (opposite 12; Figure 3) of the process chamber (11; Figure 3) in the sidewall diametrically opposed from the selected one of the sidewalls (12; Figure 3), wherein the first (12; Figure 3) and second (opposite 12; Figure 3) sidewall openings define an entire flow path (volume inside 11) of the gas and/or the reactant flow into and out of the process chamber (11; Figure 3) – claim 1
- x. wherein the inlet manifold assembly (14, 15a, not including 12; Figure 3) comprises a flow-shaping portion (15a; Figure 3) adapted to laterally elongate a gas and/or a reactant flow into the process chamber (11; Figure 3), wherein the fluid communication between the inlet manifold assembly (14, 15a, not including 12; Figure 3) and the first sidewall opening (12; Figure 3) of the process chamber (11; Figure 3) is free from a baffle plate – claim 1
- xi. wherein the flow-shaping portion (15a; Figure 3) of the inlet manifold assembly (14, 15a, not including 12; Figure 3) is adapted to introduce the gas and/or reactant flow into the

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- process chamber (11; Figure 3) at about a plane parallel to a surface of the substrate (56; Figure 3,4), as claimed by claim 2
- xii. wherein the flow-shaping portion (15a; Figure 3) is triangularly shaped, as claimed by claim 3
- xiii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the inlet manifold assembly (14, 15a, not including 12; Figure 3) further comprises a flow restrictor (12,12a; Figure 3) attached to an opening of the flow-shaping portion (15a; Figure 3), as claimed by claim 11
- xiv. The reactor assembly according to Claim 1, further comprising a baffle plate (12; Figure 3) disposed about an opening of the flow-shaping portion (15a; Figure 3), as claimed by claim 16
- xv. an inlet manifold assembly (14, 15a, not including 12; Figure 3) in fluid communication with a first sidewall opening (12; Figure 3) of the process chamber (11; Figure 3) in a selected one of the sidewalls (12; Figure 3), wherein the inlet manifold assembly (14, 15a, not including 12; Figure 3) comprises a flow-shaping portion (15a; Figure 3) adapted to laterally elongate a gas and/or a reactant flow into the process chamber (11; Figure 3), and an exhaust manifold assembly (13, 16, 17; Figure 3) in fluid communication with a second sidewall opening (opposite 12; Figure 3) of the process chamber (11; Figure 3) in the sidewall diametrically opposed from the selected one of the sidewalls (12; Figure 3) wherein the first (12; Figure 3) and second (opposite 12; Figure 3) sidewall openings define an entire flow path (volume inside 11) of the gas and/or the reactant flow into and out of the process chamber (11; Figure 3) – claim 32

It would have been obvious to one of ordinary skill in the art at the time the invention was made to replace Halpin's inlet manifold assembly (112, 114, 116; Figure 2) with Hoke's inlet manifold assembly (14, 15a, not including 12; Figure 3) and add Tanaka's exhaust control system (V1-V4, "MC"; Figure 4; column 4, lines 31-58).

Motivation to replace Halpin's inlet manifold assembly (112, 114, 116; Figure 2) with Hoke's inlet manifold assembly (14, 15a, not including 12; Figure 3) and add Tanaka's exhaust control system (V1-V4, "MC"; Figure 4; column 4, lines 31-58) is for promoting favorable flow characteristics resulting in uniform depositions as taught by Hoke (column 8, lines 5-10; column 3; lines 34-60) and Tanaka (column 9,10).

4. Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over Halpin; Michael W. (US 6143079 A), Tanaka; Hitoshi (US 5091207 A), and Hoke; William E. et al (US 5077875 A) in view of Mikio Takagi (JP02-152251¹). Halpin, Tanaka, and Hoke are discussed above. Halpin, Tanaka, and Hoke do not teach that the bottom wall of the base unit is adapted to be stackedly attached to a second reactor assembly. Mikio Takagi teaches, per the translation, a vertical semiconductor manufacturing system (Page 2) including base units (2) adapted to be stackedly attached to plural reactor assemblies (Figure 1).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to reproduce and vertically stack the Halpin, Tanaka, and Hoke reactor assembly as taught by Mikio Takagi.

¹ Refer to STIC Translation

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Motivation to reproduce and vertically stack the Halpin, Tanaka, and Hoke reactor assembly as taught by Mikio Takagi is to minimize and effectively utilize expensive clean room space (page 7).

5. Claims 7, and 17-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Halpin; Michael W. (US 6143079 A), Tanaka; Hitoshi (US 5091207 A), and Hoke; William E. et al (US 5077875 A) in view of Chazee; Jean-Jacques (US 5190592 A). Halpin, Tanaka, and Hoke are discussed above. Hoke further teaches wherein the flow restrictor (12,12a; Figure 3) comprises a plate (12; Figure 3) having at least one passageway (12a), as claimed by claim 18. Hoke further teaches wherein the flow restrictor (12,12a; Figure 3) comprises a rectangularly shaped plate (12; Figure 3) having a length dimension greater than a height dimension (Figure 3), - claim 19

Halpin, Tanaka, and Hoke do not teach the exhaust manifold (124; Figure 2) assembly comprises an exhaust receiving portion and a flow restrictor, wherein the flow restrictor is affixed to an opening of the exhaust receiving portion and is adapted to restrict the gas and/or reactant flow through the opening from the process chamber into the exhaust receiving portion. Halpin and Halpin, Tanaka, and Hoke do not teach the reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 7, wherein the exhaust receiving portion is triangularly shaped.

Chazee teaches a similar film deposition chamber over substrates (Figure 1; column 1, lines 5-17, 43-66) including an exhaust receiving portion (24; column 2, lines 9-12) that is triangularly shaped.

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It would have been obvious to one of ordinary skill in the art at the time the invention was made to replace the Halpin, Tanaka, and Hoke exhaust receiving portion with Chazee's exhaust receiving portion that is triangularly shaped and dimensionally optimized as taught by Chazee.

Motivation to replace the Halpin and Hoke exhaust receiving portion with Chazee's exhaust receiving portion that is triangularly shaped and dimensionally optimized as taught by Chazee is to "regulate the overflow and suction rate of the residual vapour phase" (column 2, lines 9-12). It is well established that changes in apparatus dimensions are within the level of ordinary skill in the art. (Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert. denied, 469 U.S. 830, 225 USPQ 232 (1984); In re Rose, 220 F.2d 459, 105 USPQ 237 (CCPA 1955); In re Rinehart, 531 F.2d 1048, 189 USPQ 143 (CCPA 1976); See MPEP 2144.04)

6. Claims 8 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Halpin; Michael W. (US 6143079 A), Tanaka; Hitoshi (US 5091207 A), and Hoke; William E. et al (US 5077875 A) in view of Costello; Simon et al. (US 6583638 B2). Halpin, Tanaka, and Hoke are discussed above. None of Halpin, Tanaka, and Hoke teach:

- i. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the support (36/56 interface; Figure 2) of the chuck assembly (36; Figure 2) comprises a means for regulating a temperature of the substrate (56; Figure 3,4), as claimed by claim 8
- ii. The reactor assembly (Figure 2, 4; column 8; lines 15-23; column 9; line 61 - column 10; line 9) according to Claim 1, wherein the support (36/56 interface; Figure 2) further comprises a resistance heating element and a cooling passage, as claimed by claim 9

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Costello teaches a chuck (Figure 2) with resistance heaters (claim 7) and coolant lines (27; Figure 2).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to replace the Halpin, Tanaka, and Hoke chuck with Costello chuck.

Motivation to replace the Halpin, Tanaka, and Hoke chuck with Costello chuck is to control substrate temperature during processing as taught by Costello (column 1, lines 18-36).

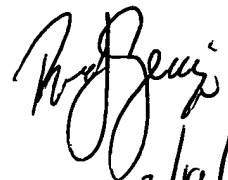
7. Claim 20 is rejected under 35 U.S.C. 103(a) as being unpatentable over Halpin; Michael W. (US 6143079 A), Tanaka; Hitoshi (US 5091207 A), and Hoke; William E. et al (US 5077875 A) and Chazee; Jean-Jacques (US 5190592 A), in view of Won et al (USPat. 6,355,108 B1). Halpin, Tanaka, Hoke, and Chazee are discussed above. Halpin, Tanaka, Hoke, and Chazee do not teach an exhaust flow restrictor made of anodized aluminum. Won teaches anodized aluminum parts (22) in a film deposition chamber (Figure 3; column 6, lines 8-15).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to fabricate the Halpin, Tanaka, Hoke, and Chazee rectangular aperture from anodized aluminum as taught by Won.

Motivation to fabricate the Halpin, Tanaka, Hoke, and Chazee rectangular aperture from anodized aluminum as taught by Won is to fabricate Hoke's rectangular aperture from an alternate and equivalent material.

Conclusion

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Rudy Zervigon whose telephone number is (571) 272-1442. The examiner can normally be reached on a Monday through Thursday schedule from 8am through 7pm. The official fax phone number for the 1763 art unit is (571) 273-8300. Any Inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Chemical and Materials Engineering art unit receptionist at (571) 272-1700. If the examiner can not be reached please contact the examiner's supervisor, Parviz Hassanzadeh, at (571) 272-1435.


3/12/6



**PARVIZ HASSANZADEH
SUPERVISORY PATENT EXAMINER**